

## HEX INVERTER

## FEATURES

- Output capability: standard
- $I_{CC}$  category: SSI

## GENERAL DESCRIPTION

The 74HC/HCT04 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT04 provide six inverting buffers.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
$t_{PHL}/t_{PLH}$	propagation delay $nA$ to $nY$	$C_L = 15 \text{ pF}$ $V_{CC} = 5 \text{ V}$	7	8	ns
$C_I$	input capacitance		3.5	3.5	pF
$C_{PD}$	power dissipation capacitance per gate	notes 1 and 2	21	24	pF

GND = 0 V;  $T_{amb} = 25^\circ\text{C}$ ;  $t_r = t_f = 6 \text{ ns}$

## Notes

1. CPD is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = CPD \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz       $C_L$  = output load capacitance in pF  
 $f_o$  = output frequency in MHz       $V_{CC}$  = supply voltage in V  
 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs

2. For HC the condition is  $V_I = \text{GND to } V_{CC}$   
 For HCT the condition is  $V_I = \text{GND to } V_{CC} - 1.5 \text{ V}$

## PACKAGE OUTLINES

14-lead DIL; plastic (SOT27)

14-lead mini pack; plastic (SO14; SOT108A)

## PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A to 6A	data inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	data outputs
7	GND	ground (0 V)
14	$V_{CC}$	positive supply voltage

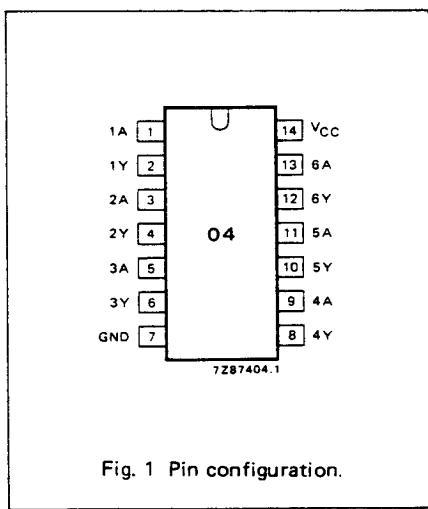


Fig. 1 Pin configuration.

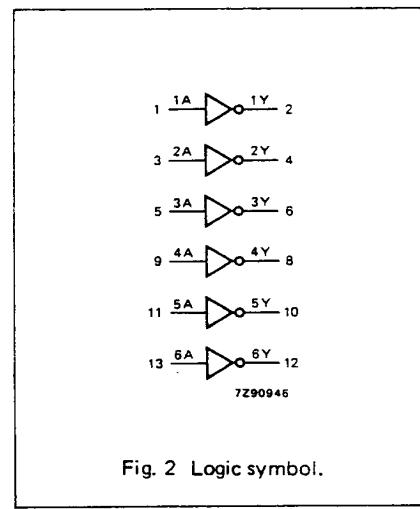


Fig. 2 Logic symbol.

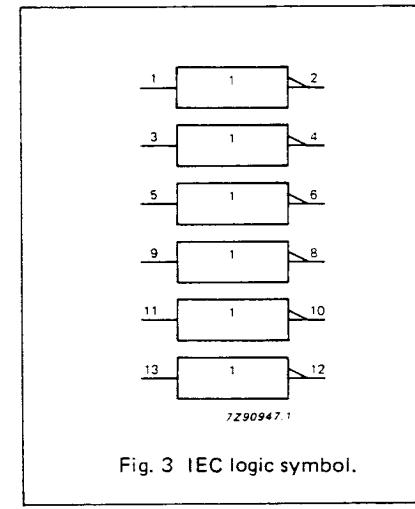
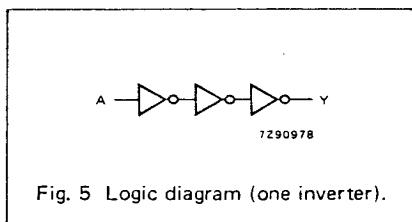
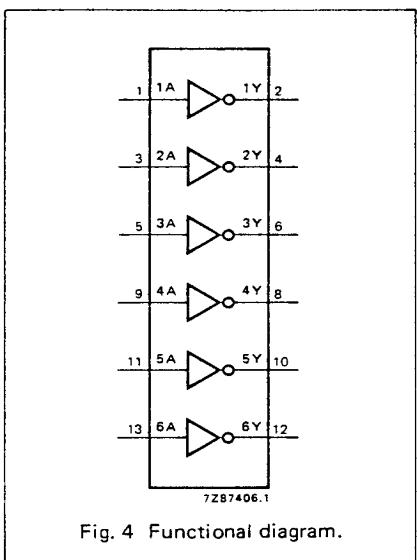


Fig. 3 IEC logic symbol.



#### FUNCTION TABLE

INPUT	OUTPUT
nA	nY
L	H
H	L

H = HIGH voltage level

L = LOW voltage level

#### DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

I<sub>CC</sub> category: SSI

#### AC CHARACTERISTICS FOR 74HC

GND = 0 V; t<sub>r</sub> = t<sub>f</sub> = 6 ns; C<sub>L</sub> = 50 pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS				
		74HC								V <sub>CC</sub> V	WAVEFORMS			
		+25			-40 to +85		-40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay nA to nY		25 9 7	85 17 14		105 21 18		130 26 22	ns	2.0 4.5 6.0	Fig. 6			
t <sub>THL</sub> / t <sub>TLH</sub>	output transition time		19 7 6	75 15 13		95 19 16		110 22 19	ns	2.0 4.5 6.0	Fig. 6			

**DC CHARACTERISTICS FOR 74HCT**

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: standard

I<sub>CC</sub> category: SSI**Note to HCT types**

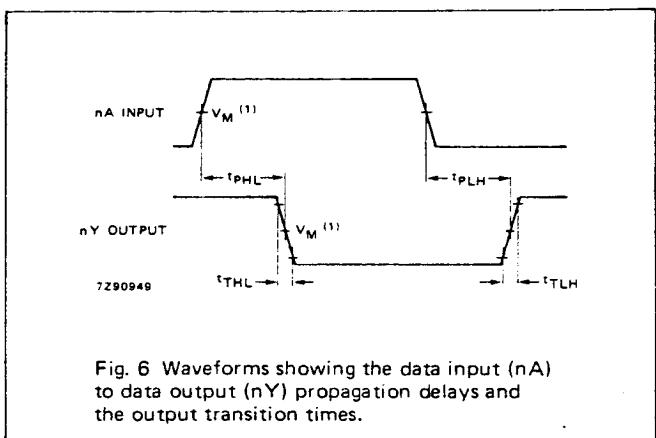
The value of additional quiescent supply current ( $\Delta I_{CC}$ ) for a unit load of 1 is given in the family specifications.  
 To determine  $\Delta I_{CC}$  per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
nA	1.20

**AC CHARACTERISTICS FOR 74HCT**GND = 0 V; t<sub>r</sub> = t<sub>f</sub> = 6 ns; C<sub>L</sub> = 50 pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS			
		74HCT							V <sub>CC</sub> V	WAVEFORMS		
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay nA to nY		10	19		24		29	ns	4.5	Fig. 6	
t <sub>THL</sub> / t <sub>TLH</sub>	output transition time		7	15		19		22	ns	4.5	Fig. 6	

AC WAVEFORMS



Note to AC waveforms

(1) HC :  $V_M = 50\%$ ;  $V_I = \text{GND to } V_{CC}$ .  
HCT:  $V_M = 1.3 \text{ V}$ ;  $V_I = \text{GND to } 3 \text{ V}$ .